

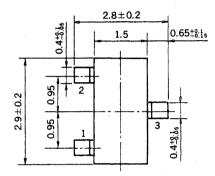
# SILICON SWITCHING DIODES

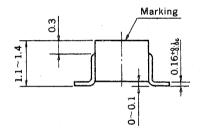
**1S2835,1S2836** 

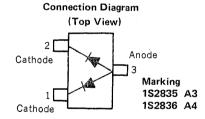
## **HIGH SPEED SWITCHING** SILICON EPITAXIAL DOUBLE DIODES: COMMON ANODE MINI MOLD

#### PACKAGE DIMENSIONS

in millimeters







#### **FEATURES**

- Low capacitance: C<sub>t</sub> = 2.5 pF TYP.
- High speed switching: t<sub>rr</sub> = 4.0 ns MAX.
- Wide applications including switching, limitter, clipper.
- Double diode configuration assures economical use.

#### ABSOLUTE MAXIMUM RATINGS

Maximum Voltages and Currents (Ta = 25 °C)

		1S2835	1S2836	
Peak Reverse Voltage	$V_{RM}$	35	75	V
DC Reverse Voltage	$V_{R}$	30	50	, V
Surge Current (1 $\mu$ s)*	IFSM	6.0	6.0	Α
Surge Current (1 $\mu$ s)	FSM	4.0	4.0	Α
Peak Forward Current*	I <sub>FM</sub>	450	450	mΑ
Peak Forward Current	IFM	300	300	mΑ
Average Rectified Current*	lo	150	150	mΑ
Average Rectified Current	lo	100	100	mΑ
Maximum Temperatures				
Junction Temperature	$T_{j}$	125	125	°C
Storage Temperature Range	$T_{stg}$	-55 to +125	-55 to $+125$	°C
Thermal Resistance				
Junction to Ambient*	$R_{th(j-a)}$	1.0	1.0	°C/mW
Junction to Ambient	$R_{th(j-a)}$	0.67	0.67	°C/mW

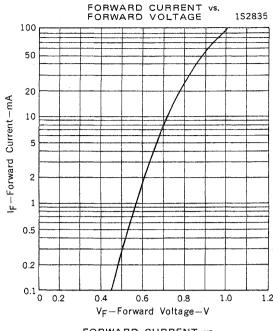
<sup>\*</sup> Both diodes loaded simultaneously.

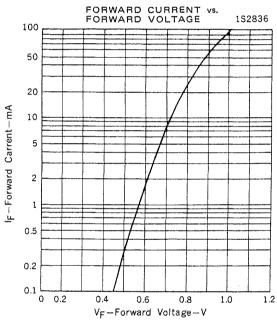
## ELECTRICAL CHARACTERISTICS (Ta = 25 °C)

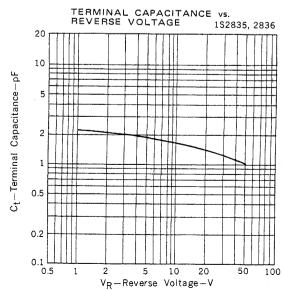
CHARACTERISTIC	SYMBOL	1S2835 (A3)		1S2836 (A4)			UNIT	TEST CONDITIONS	
		MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Forward Voltage	V <sub>F1</sub>		0.72	1.0		0.72	1.0	V	lp = 10 mA
	V <sub>F2</sub>		0.88	1.1		0.88	1.1	٧	IF = 50 mA
	V <sub>F3</sub>		1.0	1.2		1.0	1.2	V	I <sub>F</sub> = 100 mA
Reverse Current	IR			0.1				μΑ	V <sub>R</sub> = 30 V
	1 <sub>R</sub>						0.1	μА	V <sub>R</sub> = 50 V
Capacitance	Ct		2.5	4.0		2.5	4.0	рF	V <sub>R</sub> = 0, f = 1.0 MHz
Reverse Recovery Time	t <sub>rr</sub>			4.0			4.0	ns	See Test Circuit.

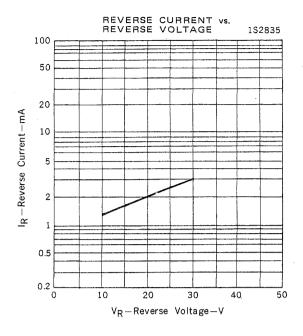
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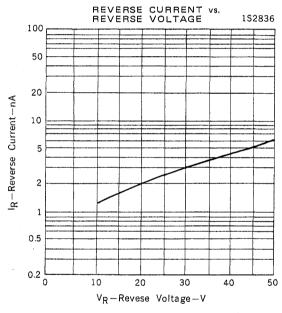
## TYPICAL ELECTRICAL CURVES (Ta = 25 °C)

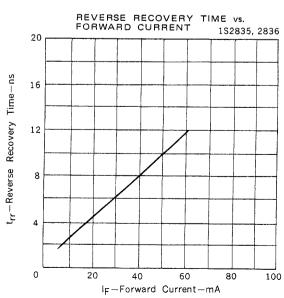




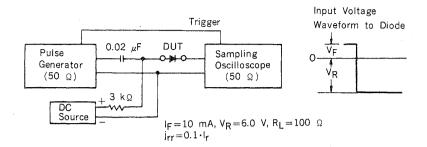


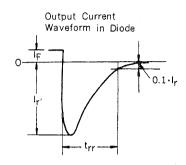






### REVERSE RECOVERY TIME (trr) TEST CIRCUIT





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